

ETF11-050

Bipolar Independent Transistor Power Module

Collmer Semiconductor, Inc.

Isolated Case (Y/N)=Yes

Circuits Per Package=1

V(BR)CEO (V)=500

V(BR)CBO (V)=600

I(C) Abs. (A) Collector Current=20

Absolute Max. Power Diss. (W)=120

R(thJC) ($\text{j} \bar{a}C/W$)=1.0

h(FE) Min. Static Current Gain=8.0

@I(C) (A) (Test Condition)=12

@VCE (test)=5.0

V(CE)sat Max. (V)=5.0

@I(C) (A) (Test Condition)=12

@I(B) (A) (Test Condition)=1.5

t(r) Max. (s) Rise time=1.0u

t(f) Max. (s) Fall time.=1.0u

Package=T0-238var